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# Broadband ultraviolet to near infrared conversion in $\text{Eu}^{2+}$ , $\text{Nd}^{3+}$ co-doped $\text{SrAl}_2\text{O}_4$

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In this study, we investigated the quantum cutting (QC) mechanism in  $\text{Eu}^{2+}$ - $\text{Nd}^{3+}$ -co-doped  $\text{SrAl}_2\text{O}_4$  microcrystals by fluorescence spectroscopy and decay lifetime analysis. In this material, the near-infrared (NIR) emissions of  $\text{Nd}^{3+}$  in the range of 800–1200 nm were enhanced under the excitation of the  $\text{Eu}^{2+}:4f^7 \rightarrow 4f^65d^1$  transition radiation. The lifetime of the  $5d^1$  level of  $\text{Eu}^{2+}$  decreased with the increase in the  $\text{Nd}^{3+}$  concentration. These results verified the occurrence of cooperative energy transfer (CET) from the  $\text{Eu}^{2+}:5d^1$  excited state to the  $\text{Nd}^{3+}:^4F_{3/2}$  level, by which one absorbed ultraviolet-visible photon was converted to two NIR photons with an optimal quantum efficiency (QE) of approximately 177.1%. Therefore, this broadband QC material paves the way for a further increase in the conversion efficiency of c-Si solar cells.

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## 1. Introduction

With the rapid development of the global economy and industry the traditional energy resources face the problems of exhaustion and serious environmental pollution. Solar energy is a representative alternative clean energy with significant advantages: it is abundant, non-pollution, and inexhaustible. The solar energy supplied from the sun is approximately 10 000 times higher than the current energy consumption on the Earth.<sup>1</sup> Therefore, it becomes the most promising energy resource of interest to national governments. Since its development in the previous century, the silicon solar cell has been extensively employed in various industries owing to its low cost, optimized preparation technology, and high efficiency.<sup>2–4</sup> However, silicon has a band-gap of 1.12 eV and thus it can only absorb near-infrared (NIR) photons in the solar spectrum range of 900–1200 nm; the majority of the energy in the ultraviolet-visible (UV-Vis) region is lost owing to thermalization of charge carriers, referred to as spectral mismatch, which significantly restricts the conversion efficiency of the c-Si solar cell to 19%. The efficiency is significantly lower than the theoretical value of 31.0% reported by Shockley.<sup>5</sup> Extensive studies have been performed to decrease the energy loss caused by spectral mismatch and to increase the device efficiency.<sup>6–10</sup>

However, most methods have disadvantages of high costs and complex preparation processes, which limit their applications in solar cells. Quantum cutting (QC) is a promising method to increase the efficiencies of solar cells. According to the design of a luminescent layer on top of the solar cell, one incident UV-Vis photon was converted to two NIR photons, efficiently absorbed by the c-Si solar cell. Therefore, the energy loss caused by thermalization could be effectively suppressed and thus the efficiency of the solar cell could be increased.<sup>11,12</sup>

Rare-earth (RE) ions are optimal candidates for QC owing to their abundant energy levels. Considering the energy levels of lanthanides, the  $\text{Yb}^{3+}$  ion has a single excited state at approximately 10 000  $\text{cm}^{-1}$  and exclusively emits NIR photons at  $\sim 1000$  nm, which correspond to the strongest spectral response of c-Si. Therefore, many studies have been focused on the RE- $\text{Yb}^{3+}$  co-doped system (RE =  $\text{Eu}^{2+}$ ,<sup>13,14</sup>  $\text{Ce}^{3+}$ ,<sup>15–17</sup>  $\text{Pr}^{3+}$ ,<sup>18–20</sup>  $\text{Er}^{3+}$ ,<sup>21,22</sup> and  $\text{Tb}^{3+}$  (ref. 23 and 24)) in recent years. The RE ion absorbs one incident UV-Vis photon and transfer its energy to two  $\text{Yb}^{3+}$  ions by cooperative energy transfer (CET) with an optimal QE of approximately 200%.<sup>25,26</sup> However, the NIR luminescent intensity of the  $\text{Yb}^{3+}$  ion is significantly lower than that of its counterpart in the UV-Vis region. In addition, charge transfer state (CTS) could emerge for  $\text{Yb}^{2+}\text{-O}^{2-}$  or  $\text{Yb}^{3+}\text{-O}^{2-}$ .<sup>13,16</sup> These disadvantages have decreased the practical QE for the RE- $\text{Yb}^{3+}$  couple and further limited its application to solar cells.

$\text{Nd}^{3+}$  is another RE ion with NIR luminescence in the range of 800–1500 nm. The  $\text{Nd}^{3+}$  fluorescence intensity at NIR wavelengths is higher than that of  $\text{Yb}^{3+}$ ; in addition, no CTS emerges during the ET process. The NIR luminescence of  $\text{Nd}^{3+}$  is in the wavelength range of 800–1500 nm, significantly broader than that of  $\text{Yb}^{3+}$  of 900–1100 nm; and the spectral response range to c-Si could be broadened. Therefore, the RE-

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$\text{Nd}^{3+}$  couples have larger potentials to increase the efficiency of c-Si. However, only a limited number of studies analyzed the RE- $\text{Nd}^{3+}$  co-doped system and its QC property.<sup>27,28</sup> The  $\text{Eu}^{2+}$  ion is a typical broadband sensitizer owing to the allowed  $4f \rightarrow 5d$  transition; its fluorescence spectra have been controlled by the crystal field of the matrix. The emission spectrum of the  $\text{Eu}^{2+}$  ion in a  $\text{SrAl}_2\text{O}_4$  matrix well overlaps with the  $\text{Nd}^{3+}$  excitation spectrum. The energy of the  $\text{Eu}^{2+}:4f^7 \rightarrow 4f^65d^1$  transition is twice that of the  $\text{Nd}^{3+}:4f_{3/2} \rightarrow 4f_{11/4}$  transition, which enables a DC process between  $\text{Eu}^{2+}$  and  $\text{Nd}^{3+}$ .

In this study, we report an efficient QC process in  $\text{Eu}^{2+}$ - $\text{Nd}^{3+}$ -co-doped  $\text{SrAl}_2\text{O}_4$  microcrystals. The fluorescence spectra of  $\text{Eu}^{2+}$  and  $\text{Nd}^{3+}$  were recorded to verify the ET process. The dependence of the visible and NIR emission intensities on the  $\text{Nd}^{3+}$  concentration was studied to investigate the ET mechanism. The decay lifetime of  $\text{Eu}^{2+}$ , ET rate, and QE were also evaluated. The aim of this study was to utilize the broadband UV-Vis part of the solar spectrum to enhance the NIR responses of c-Si solar cells.

## 2. Experimental

Microcrystals of  $\text{SrAl}_2\text{O}_4:0.01\text{Eu}^{2+},x\text{Nd}^{3+}$  ( $x = 0, 0.01, 0.02, 0.05, 0.10, 0.15$  in mol) were synthesized by a conventional solid-state reaction method, using  $\text{SrCO}_3$  (99.5%),  $\text{Al}_2\text{O}_3$  (99.5%),  $\text{Eu}_2\text{O}_3$  (99.9%),  $\text{Nd}_2\text{O}_3$  (99.9%), and  $\text{H}_3\text{BO}_3$  (99.5%) as raw materials. All of the raw materials were dried at 100–150 °C for 10–12 h in the drying oven to remove the residual water. The starting materials were weighed by the designed stoichiometric proportion, a 5 mol% excess of  $\text{H}_3\text{BO}_3$  was added as a flux, and then wet-mixed with the absolute alcohol (>97%) for 2–3 h in the agate mortar. After mixing, the powder was dried in the oven for 12 h at 100 °C. The powder was sintered in a corundum crucible under reducing atmosphere, which was supplied by the mixed gas of 95% argon and 5% hydrogen. Reactions were performed in a vertical high-temperature tube furnace at 1200 °C for 3–5 h, and then cooled to room temperature. Both of the heating and annealing rates are 3 °C  $\text{min}^{-1}$ .

In order to identify the phase structures of the as-synthesized samples, powder X-ray diffraction (XRD) measurements were performed using a Rigaku D/max-2000 powder diffractometer with Cu  $K_\alpha$  radiation (1.5405 Å) in the range of 20–70°. The optical properties were measured using an Edinburgh Instruments FLS920 spectrofluorometer; excitation and emission spectra, decay curves, and lifetimes of the products were obtained. All of the measurements were performed at room temperature.

## 3. Results and discussion

### 3.1 Structure behavior

Fig. 1 shows XRD patterns of the products. Compared with the standard data (JCPDS card no. 34-0379), all of the diffraction peaks corresponded to a pure monoclinic  $\alpha$ - $\text{SrAl}_2\text{O}_4$  phase with lattice parameters of  $a = 5.069(2)$  Å,  $b = 8.799(7)$  Å, and  $c = 9.759(9)$  Å. In addition, no allotropic or impurity phases appeared in the patterns, which implies that the pure  $\alpha$ - $\text{SrAl}_2\text{O}_4$

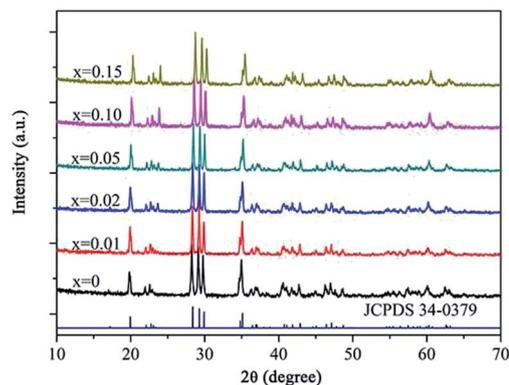


Fig. 1 The XRD patterns of  $\text{Eu}^{2+}$  single doped and  $\text{Eu}^{2+},\text{Nd}^{3+}$  codoped  $\text{SrAl}_2\text{O}_4$ .

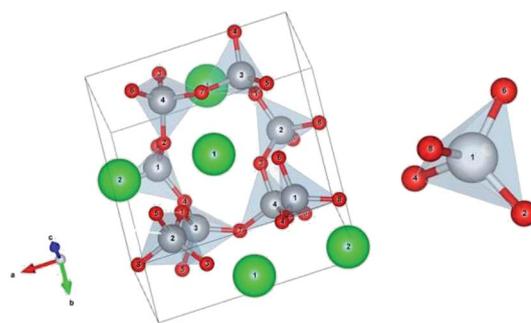


Fig. 2 Crystalline structure of  $\alpha$ - $\text{SrAl}_2\text{O}_4$ .

crystalline phase was obtained and that the  $\text{Eu}^{2+}$  and  $\text{Nd}^{3+}$  ions were thoroughly incorporated into the matrix. Fig. 1 also shows that the diffraction peaks shifted to higher angles  $2\theta$  with the increase in the  $\text{Nd}^{3+}$  concentration. The reason is that  $\text{Eu}^{2+}$  (112 pm) and  $\text{Nd}^{3+}$  (99.5 pm) ions substituted  $\text{Sr}^{2+}$  (113 pm) ions in  $\alpha$ - $\text{SrAl}_2\text{O}_4$ , and the radii of the RE ions are smaller than that of  $\text{Sr}^{2+}$ . According to the Scherrer's equation  $n\lambda = 2d \sin \theta$ , therefore, the interplanar spacing decreased.

In order to further interpret the substitution of  $\text{Sr}^{2+}$  by RE ions, Fig. 2 shows the crystalline structure of the monoclinic  $\alpha$ - $\text{SrAl}_2\text{O}_4$ . In the crystal lattice of  $\alpha$ - $\text{SrAl}_2\text{O}_4$ , each aluminium (Al) atom is surrounded by four oxygen (O) atoms, forming  $\text{AlO}_4$  tetrahedra. Furthermore, the  $\text{AlO}_4$  tetrahedra combine with each other by Al–O bonds to form a six-membered ring with a cavity volume of approximately  $398 \times 10^6 \text{ pm}^3$ ; the  $\text{Sr}^{2+}$  ions are located at the centers of the rings. The hexagon rings supply a sufficient space to facilitate the substitution of  $\text{Sr}^{2+}$  ions by RE ions.

### 3.2 ET between $\text{Eu}^{2+}$ and $\text{Nd}^{3+}$

Fig. 3 gives the fluorescent spectra of the  $\text{SrAl}_2\text{O}_4:0.01\text{Eu}^{2+}$  and  $\text{SrAl}_2\text{O}_4:0.01\text{Nd}^{3+}$  samples. Fig. 3(a) and (b) show that both the excitation and emission spectra of  $\text{Eu}^{2+}$  ion exhibit typical broadband characteristic in  $\text{SrAl}_2\text{O}_4$  matrix, covering the UV range of 250–400 nm and visible range of 450–600 nm, respectively. In the  $\text{SrAl}_2\text{O}_4:0.01\text{Nd}^{3+}$  sample, the excitation spectrum was obtained by monitoring the 1064 nm emission, which is in



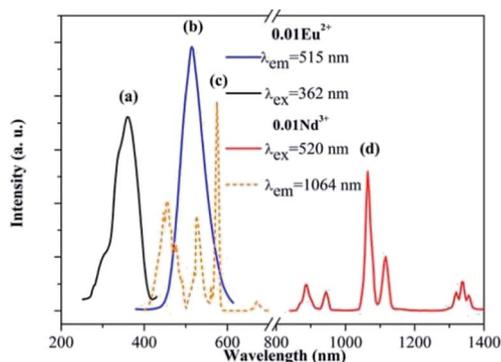


Fig. 3 The fluorescence spectra of  $\text{SrAl}_2\text{O}_4:0.01\text{Eu}^{2+}$  and  $\text{SrAl}_2\text{O}_4:0.01\text{Nd}^{3+}$  samples. (a) The excitation spectrum of  $\text{Eu}^{2+}$  ( $\lambda_{\text{em}} = 515$  nm) in the  $\text{SrAl}_2\text{O}_4:0.01\text{Eu}^{2+}$  sample, (b) the emission spectrum of  $\text{Eu}^{2+}$  ( $\lambda_{\text{ex}} = 362$  nm) in the  $\text{SrAl}_2\text{O}_4:0.01\text{Eu}^{2+}$  sample, (c) the excitation spectrum of  $\text{Nd}^{3+}$  ( $\lambda_{\text{em}} = 1064$  nm) in the  $\text{SrAl}_2\text{O}_4:0.01\text{Nd}^{3+}$  sample, (d) the emission spectrum of  $\text{Nd}^{3+}$  ( $\lambda_{\text{ex}} = 520$  nm) in the  $\text{SrAl}_2\text{O}_4:0.01\text{Nd}^{3+}$  sample.

the range of 400–700 nm. It was noticed that the excitation peak of  $\text{Nd}^{3+}$  at 520 nm was overlapped well with the emission spectrum of  $\text{Eu}^{2+}$  ion, implying the possible ET from  $\text{Eu}^{2+}$  to  $\text{Nd}^{3+}$  in  $\text{SrAl}_2\text{O}_4$  matrix. Moreover, under the 520 nm excitation, the representative emission spectrum of  $\text{Nd}^{3+}$  emerges in the NIR range of 800–1200 nm correspondence with the strongest absorption of c-Si solar cells.

In order to confirm the ET process between  $\text{Eu}^{2+}$  and  $\text{Nd}^{3+}$ , the dependence of the emission intensities in both visible and NIR regions on the doping concentration of  $\text{Nd}^{3+}$  is shown in Fig. 4. All of the emission spectra were recorded under the 362 nm excitation ( $\text{Eu}^{2+}:4f^65d^1 \rightarrow 4f^7$  allowed transition). In the visible region, the emission intensities of  $\text{Eu}^{2+}$  monotonously decreased with the increase in the  $\text{Nd}^{3+}$  concentration. Since the concentration of  $\text{Eu}^{2+}$  was fixed to be 0.01 mol in every sample, the decreasing of emission intensity was ascribed to the ET from  $\text{Eu}^{2+}$  to  $\text{Nd}^{3+}$ . On the contrary, the NIR emission intensities of  $\text{Nd}^{3+}$  rapidly increased with the  $\text{Nd}^{3+}$  concentration in the range of 0.01 to 0.10 owing to the ET from  $\text{Eu}^{2+}$  to  $\text{Nd}^{3+}$ . With the further increase in the  $\text{Nd}^{3+}$  concentration, at 0.15, the emission intensity of  $\text{Nd}^{3+}$  was significantly lower than that of the 0.10

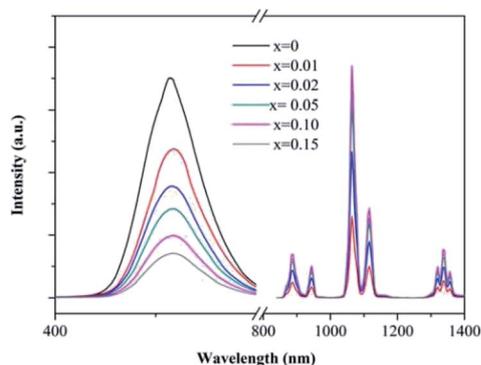


Fig. 4 Concentration-dependent emission spectra of  $\text{SrAl}_2\text{O}_4:0.01\text{Eu}^{2+}, x\text{Nd}^{3+}$  ( $x = 0-0.15$ ) under 362 nm excitation.

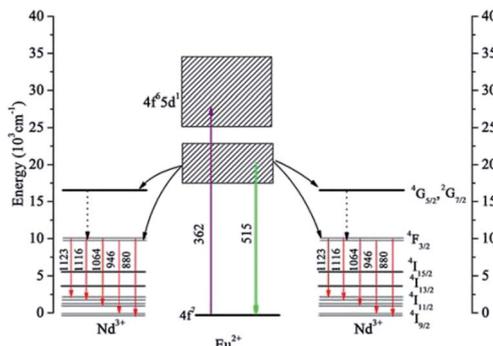


Fig. 5 Schematic energy level diagrams of  $\text{Eu}^{2+}$ ,  $\text{Nd}^{3+}$ , showing the QC process between  $\text{Eu}^{2+}$  and  $\text{Nd}^{3+}$  under 362 nm excitation.

sample, which indicates that concentration quenching (CQ) occurred among the  $\text{Nd}^{3+}$  ions.

### 3.3 ET mechanism

In order to illustrate the ET mechanism in detail, schematic energy diagrams of  $\text{Eu}^{2+}$  and  $\text{Nd}^{3+}$  are presented in Fig. 5. As the excitation state of  $\text{Eu}^{2+}:4f^65d^1$  was split to two energy levels in the  $\text{SrAl}_2\text{O}_4$  matrix, the ET process from  $\text{Eu}^{2+}$  to  $\text{Nd}^{3+}$  can be described as follow. Under the 362 nm excitation, the  $\text{Eu}^{2+}:4f^7 \rightarrow 4f^65d^1$  transition occurred and the photons populated the higher  $4f^65d^1$  level, which then relaxed to the lower  $4f^65d^1$  state by Stokes shift. Majority of the photons, which occupied the  $\text{Eu}^{2+}:4f^65d^1$  (lower) state, transferred their energies to the  $\text{Nd}^{3+}:4f_{3/2}$  state. The energy gap of the  $\text{Eu}^{2+}:4f^65d^1 \rightarrow 4f^7$  transition is approximately twice that of the  $\text{Nd}^{3+}:4f_{3/2} \rightarrow 4f_{11/2}$  transition; therefore, this ET process is proposed as a DC process with a CET mechanism. In addition, transition of  $\text{Nd}^{3+}:4f_{3/2} \rightarrow 4f_{9/2}$  also occurred due to the sensitization of  $\text{Eu}^{2+}$ , during this process,  $\text{Eu}^{2+}$  ion absorbed on incident visible photon and transferred its energy to  $\text{Nd}^{3+}$ , emitted one NIR photon. Therefore, the 880 nm and 946 nm NIR emission intensities of  $\text{Nd}^{3+}$  were enhanced.

Fig. 6 displays the spectral response of  $\text{Nd}^{3+}$  ion to solar spectrum and silicon absorption. It can be seen that the emission spectrum of  $\text{Nd}^{3+}$  lies in the range of 800–1200 nm, which is much broader than that of  $\text{Yb}^{3+}$  and meets the strongest spectral response of c-Si solar cells. Moreover, the NIR emission of  $\text{Nd}^{3+}$  has been enhanced by the CET process, and then efficiently utilized by the c-Si solar cell. In addition, the excitation spectrum of  $\text{Nd}^{3+}$  in the range of 400–700 nm is a typical broadband, enabling absorption of the strongest emission of the solar spectrum. In a word, the  $\text{SrAl}_2\text{O}_4:\text{Eu}^{2+}, \text{Nd}^{3+}$  phosphor can convert the UV-Vis broadband of the solar spectrum to the NIR range, which could be potentially employed to increase the conversion efficiency of c-Si solar cells by reducing the thermalization loss.

### 3.4 Decay curves and ET efficiency

The decay curves for the  $\text{Eu}^{2+}:4f^7 \rightarrow 4f^65d^1$  transition at 515 nm are plotted for different  $\text{Nd}^{3+}$  concentrations in Fig. 7. The



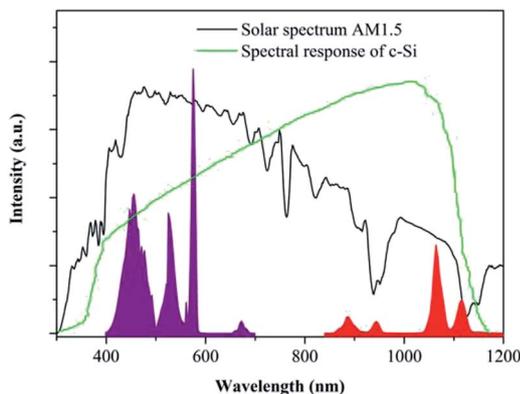


Fig. 6 The excitation and emission spectra of  $\text{SrAl}_2\text{O}_4:\text{Eu}^{2+},\text{Nd}^{3+}$ , indicating the spectral match and spectral response of  $\text{Eu}^{2+}$  and  $\text{Nd}^{3+}$ . The AM 1.5 G solar spectrum and spectral response of c-Si in this spectral region are shown in the background as references.

experimental lifetime ( $\tau_m$ ) of the  $\text{Eu}^{2+}$  515 nm emission can be calculated by:

$$\tau_m = \frac{1}{I_0} \int_0^{\infty} I(t) dt \quad (1)$$

where  $I_0$  is the luminescence intensity at  $t = 0$ , while  $I(t)$  is the luminescence intensity at  $t$  after the excitation source was cut-off. The  $\text{Eu}^{2+}$  single doped sample exhibited an approximately single-exponential decay curve with a lifetime  $\tau_m$  of 6.1  $\mu\text{s}$ . With the increase in the  $\text{Nd}^{3+}$  concentration from 0 to 0.10 mol, the decay curves gradually deviated from single-exponential curves, and the lifetime  $\tau_m$  decreased to 4.9, 3.8, 2.1, and 1.4  $\mu\text{s}$  gradually. As the  $\text{Eu}^{2+}$  concentration is set to 0.01 mol in all of the samples, the decreasing lifetime and non-single exponential decay curves were attributed to the introduction of extra decay pathways, such as the CET from  $\text{Eu}^{2+}$  to  $\text{Nd}^{3+}$ .

In order to further illuminate the ET process between  $\text{Eu}^{2+}$  and  $\text{Nd}^{3+}$ , the energy transfer (ET) rate dependence on the  $\text{Nd}^{3+}$  concentration has been investigated. Since the lifetime of  $\text{Eu}^{2+}$  (donor) decreases with the increasing in the  $\text{Nd}^{3+}$  (acceptor) concentration, the CET from  $\text{Eu}^{2+}$  to  $\text{Nd}^{3+}$  is primarily a non-

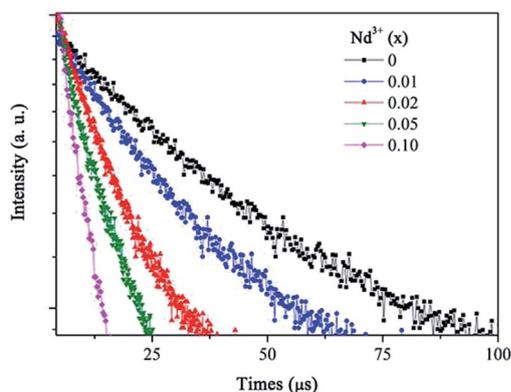


Fig. 7 Decay lifetimes of the  $\text{Eu}^{2+}:4f^65d^1 \rightarrow 4f^7$  emission (515 nm) under 362 nm excitation.

Table 1 The energy transfer efficiency ( $P_{\text{DA}}$ ) and energy transfer efficiency ( $\eta_{\text{DA}}$ ) with different  $\text{Nd}^{3+}$  concentration in  $\text{Eu}^{2+}-\text{Nd}^{3+}$  codoped  $\text{SrAl}_2\text{O}_4$  samples

$\text{Nd}^{3+}$ (mol%)	$P_{\text{DA}}$ ( $\mu\text{s}^{-1}$ )	$\eta_{\text{DA}}$ (%)
0.01	0.041	19.7
0.02	0.099	37.7
0.05	0.312	65.6
0.10	0.550	77.1

radiative process,<sup>29</sup> which can be modeled by the Forster-Dexter theory of non-radiative ET processes.<sup>30</sup> Furthermore, the dipole-dipole interaction is essential for this CET process according to previous reports.<sup>31,32</sup>

The macroscopic ET rate  $P_{\text{DA}}$  of the dipole-dipole interaction can be estimated by the lifetime of the donor ions ( $\text{Eu}^{2+}$ ) using:<sup>33</sup>

$$P_{\text{DA}} = \frac{1}{\tau} - \frac{1}{\tau_0} \quad (2)$$

where  $\tau_0$  and  $\tau$  denote the lifetimes of the donor emissions in the  $\text{Eu}^{2+}$  single-doped and  $\text{Eu}^{2+}-\text{Nd}^{3+}$  co-doped samples, respectively.

Using eqn (2), the ET rates of the  $\text{Eu}^{2+}-\text{Nd}^{3+}$  co-doped samples can be evaluated.

As the non-radiative transition in the donors can be neglected according to Dexter,<sup>30</sup> the ET efficiency ( $\eta_{\text{DA}}$ ) between  $\text{Eu}^{2+}$  and  $\text{Nd}^{3+}$  can be calculated by:<sup>34</sup>

$$\eta_{\text{DA}} = \frac{P_{\text{DA}}\tau_0}{1 + P_{\text{DA}}\tau_0} \quad (3)$$

$P_{\text{DA}}$  and  $\eta_{\text{DA}}$  are calculated as a function of the  $\text{Nd}^{3+}$  concentration and listed in Table 1. The ET rate and efficiency significantly increased upon the  $\text{Nd}^{3+}$  introduction. For the  $\text{SrAl}_2\text{O}_4:0.01\text{Eu}^{2+},0.01\text{Nd}^{3+}$  sample,  $P_{\text{DA}}$  and  $\eta_{\text{DA}}$  are 0.041  $\mu\text{s}^{-1}$  and 19.7%, respectively. With the increase in the  $\text{Nd}^{3+}$  concentration to 0.10 mol%,  $\eta_{\text{DA}}$  increases to approximately 77.1% with  $P_{\text{DA}} = 0.55 \mu\text{s}^{-1}$ . The increasing of  $P_{\text{DA}}$  and  $\eta_{\text{DA}}$  with the introduction of  $\text{Nd}^{3+}$  verified that the ET occurred from  $\text{Eu}^{2+}$  to  $\text{Nd}^{3+}$ .

In addition, the theoretical QE of the  $\text{Eu}^{2+}-\text{Nd}^{3+}$  pair was evaluated by:<sup>35</sup>

$$\text{QE} = \eta_{\text{Eu}}(1 - \eta_{\text{DA}}) + 2\eta_{\text{DA}} \quad (4)$$

where  $\eta_{\text{Eu}}$  is the QE of  $\text{Eu}^{2+}$ , which is supposed to be 1 according to ref. 14. The estimated theoretical QE are 119.7%, 137.7%, 165.6%, and 177.1% for the  $x = 0.01, 0.02, 0.05,$  and  $0.10 \text{ Nd}^{3+}$  doped samples, respectively. It is worth noting that the actual QE was lower than the theoretical value owing to the  $\text{Eu}^{2+}$  non-radiative transition.

## 4. Conclusions

A broadband NIR QC was achieved in the  $\text{SrAl}_2\text{O}_4:\text{Eu}^{2+},\text{Nd}^{3+}$  phosphors. Under the 362 nm excitation, the  $\text{Nd}^{3+}$  ion emitted two NIR photons in the range of 800–1200 nm by the CET



process from the  $\text{Eu}^{2+}:5d^1$  state to the  $\text{Nd}^{3+}:4F_{3/2}$  state. The optimal QE was 177.1% before the QC occurred. This material can efficiently utilize the broadband solar spectrum in the UV-Vis region; therefore, it might reduce the thermalization loss and thus has significant potentials to increase the conversion efficiency of c-Si solar cells.

## Conflicts of interest

There are no conflicts to declare.

## Acknowledgements

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